IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

APPLICANT:

Gormley et al.

GROUP:

2811

5780

SERIAL NO:

09/661,766

EXAMINER: Hung K.

FILED:

September 14, 2000

FOR:

A METHOD FOR FORMING A SEMICONDUCTOR DEVICE AND A SEMICONDUCTOR DEVICE FORMED BY THE METHOD OF THE M

Assistant Commissioner of Patents Washington, D.C. 20231 Mail Stop AF

Sir:

AMENDMENT AFTER FINAL

In response to the Office Action mailed April 7, 2003, please consider the following remarks:

REMARKS

Claims 1-27 are rejected under 35 USC §112, first paragraph, as not being supported by the application as filed. Furthermore, claims 12 and 34 are rejected under 35 USC §112, second paragraph as being indefinite.

Claims 28-33 and 35-39 are allowed. Claims 1, 12, and 34, and thus the remaining claims, would be allowable if amended to overcome the 35 USC §112 rejections.

The Examiner's rejections are respectfully traversed.

Before describing the essence of the invention, the problem that the invention addresses will first be briefly described.

The invention is directed towards the formation of a multi-layer semiconductor device in which components, typically, a micro-mechanical component or components are